

**10-FE06PPA030SJ07-LV82B03Z**

datasheet

**Vincotech**

<b>flowPIM 1 + PFC</b>		<b>600 V / 30 A</b>
<b>Features</b>		<b>flow 1 12 mm housing</b>
<ul style="list-style-type: none"><li>• One-phase rectifier</li><li>• Interleaved PFC circuit</li><li>• High speed IGBT in the inverter</li><li>• On-board capacitors</li><li>• Built-in NTC</li></ul>		
<b>Target applications</b>		<b>Schematic</b>
<ul style="list-style-type: none"><li>• Embedded Drives</li><li>• Heat Pumps</li><li>• HVAC</li><li>• Industrial Drives</li></ul>		
<b>Types</b>		
<ul style="list-style-type: none"><li>• 10-FE06PPA030SJ07-LV82B03Z</li></ul>		



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## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>Inverter Switch</b>				
Collector-emitter voltage	$V_{CES}$		600	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	30	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	90	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	63	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ , $V_{CC} = 400\text{ V}$ $T_j = 150^\circ\text{C}$	5	$\mu\text{s}$
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>Inverter Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	28	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	40	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	50	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>PFC Switch</b>				
Collector-emitter voltage	$V_{CES}$		650	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	29	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	90	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	68	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$



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## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>PFC Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	32	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	180	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	59	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$

## PFC Sw. Protection Diode

Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	16	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	12	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$

## Rectifier Diode

Peak repetitive reverse voltage	$V_{RRM}$		1600	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	99	A
Surge (non-repetitive) forward current	$I_{FSM}$	Single Half Sine Wave, $t_p = 10 \text{ ms}$	890	A
Surge current capability	$I_t$	$T_j = 150^\circ\text{C}$	3960	$\text{A}^2\text{s}$
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	108	W
Maximum junction temperature	$T_{jmax}$		150	$^\circ\text{C}$

## Capacitor (PFC)

Maximum DC voltage	$V_{MAX}$		630	V
Operation Temperature	$T_{op}$		-55 ... 150	$^\circ\text{C}$

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## Maximum Ratings

 $T_j = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
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### Module Properties

#### Thermal Properties

Storage temperature	$T_{stg}$		-40...+125	°C
Operation temperature under switching condition	$T_{jop}$		-40...+( $T_{jmax} - 25$ )	°C

#### Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
Isolation voltage	$V_{isol}$	AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				>12,7	mm
Clearance				7,82	mm
Comparative Tracking Index	CTI			≥ 600	

\*100 % tested in production



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		

## Inverter Switch

## Static

Gate-emitter threshold voltage	$V_{GE(\text{th})}$	$V_{CE} = V_{GE}$			0,00048	25	4,1	5,1	5,7	V
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$		15		30	25 125 150		1,73 1,97 2,01	1,8 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	600		25			1,6	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25			100	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{res}$	$f = 1 \text{ MHz}$	0	25	25	25	1050		pF	
Output capacitance	$C_{oes}$									
Reverse transfer capacitance	$C_{res}$									
Gate charge	$Q_g$	$V_{CC} = 480 \text{ V}$	15		30	25		130		nC

## Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						1,52		K/W
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## Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 8 \Omega$ $R_{goff} = 8 \Omega$	$\pm 15$	350	30	25		37		ns
Rise time	$t_r$					125		38		
Turn-off delay time	$t_{d(off)}$					150		38		
Fall time	$t_f$					25		12		
Turn-on energy (per pulse)	$E_{on}$					125		13		
Turn-off energy (per pulse)	$E_{off}$					150		15		
		$Q_{fFWD}=0,812 \mu\text{C}$ $Q_{rFWD}=1,81 \mu\text{C}$ $Q_{tFWD}=2,02 \mu\text{C}$				25		90		
						125		109		
						150		113		
						25		12		
						125		19,35		
						150		23,06		
						25		0,758		
						125		0,981		
						150		1,04		mWs
						25		0,233		
						125		0,422		
						150		0,469		mWs



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## Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max

### Inverter Diode

#### Static

Forward voltage	$V_F$				20	25 125 150	1,25	1,7 1,58 1,58	1,95 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 600$ V			25			27	$\mu$ A	

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,91		K/W
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#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt=500$ A/ $\mu$ s $di/dt=1295$ A/ $\mu$ s $di/dt=1294$ A/ $\mu$ s	$\pm 15$	350	30	25 125 150		7,86 12,39 13,22		A
Reverse recovery time	$t_{rr}$					25 125 150		200,95 276,23 327,76		ns
Recovered charge	$Q_r$					25 125 150		0,812 1,81 2,02		$\mu$ C
Reverse recovered energy	$E_{rec}$					25 125 150		0,161 0,388 0,431		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		53,57 61,27 82,45		$A/\mu$ s



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$I_D$ [A]	$T_j$ [°C]	Min	

### PFC Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0003	25	3,3	4	4,7	V
Collector-emitter saturation voltage	$V_{CEsat}$		15		30	25 125		1,97 2,25	2,22 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	650		25			40	μA
Gate-emitter leakage current	$I_{GES}$		20	0		25			120	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{ies}$	$f = 1 \text{ Mhz}$	0	25	25	25		2100		pF
Output capacitance	$C_{oes}$							45		pF
Reverse transfer capacitance	$C_{res}$							7,7		pF
Gate charge	$Q_g$	$V_{CC} = 520 \text{ V}$	15		30	25		65		nC

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,39		K/W
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#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 8 \Omega$ $R_{goft} = 8 \Omega$	0/15	400	30	25		12		ns
Rise time	$t_r$					125		12		
Turn-off delay time	$t_{d(off)}$					150		13		
Fall time	$t_f$		10/15	400	30	25		8		
Turn-on energy (per pulse)	$E_{on}$					125		8		
Turn-off energy (per pulse)	$E_{off}$					150		8		
			10/15	400	30	25		80		
						125		94		
						150		98		
			10/15	400	30	25		7,96		
						125		9,61		
						150		10,37		
			10/15	400	30	25		0,391		
						125		0,524		
						150		0,451		mWs
			10/15	400	30	25		0,086		
						125		0,207		
						150		0,332		mWs



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## Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max

### PFC Diode

#### Static

Forward voltage	$V_F$				30	25 125		2,47 2,03	2,6 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 650$ V				25			10	µA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,61		K/W
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#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt=4524$ A/µs $di/dt=4528$ A/µs $di/dt=4350$ A/µs	0/15	400	30	25		24,18		A
Reverse recovery time	$t_{rr}$					125		39,85		
Recovered charge	$Q_r$					150		45,05		
Recovered charge	$Q_r$		0/15	400	30	25		18,85		ns
Reverse recovered energy	$E_{rec}$					125		47,2		
Reverse recovered energy	$E_{rec}$					150		50,43		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		0,394		$\mu$ C
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		0,956		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		1,17		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		0,088		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		0,221		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		0,275		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		2361		A/µs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		2958		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		3147		



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$I_C$ [A]	$T_j$ [°C]	Min	Typ	Max	

### PFC Sw. Protection Diode

#### Static

Forward voltage	$V_F$				6	25 125 150	1,23	1,72 1,59 1,54	1,87 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 650$ V			25			0,1	$\mu$ A	

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						2,53		K/W
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### Rectifier Diode

#### Static

Forward voltage	$V_F$				5	25 125 150		0,83 0,69 0,656	1,1 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 1600$ V			25 150			100 2	$\mu$ A	

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,65		K/W
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### Capacitor (PFC)

#### Static

Capacitance	$C$	DC bias voltage = 0 V				25		33		nF
Tolerance							-5		5	%



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$T_j$ [°C]	Min	Typ	Max

### Thermistor

#### Static

Rated resistance	$R$					25		22		kΩ
Deviation of $R_{100}$	$A_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	$P$							5		mW
Power dissipation constant	$d$					25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3962		K
B-value	$B_{(25/100)}$	Tol. ±1 %						4000		K
Vincotech Thermistor Reference									I	

(1) Value at chip level

(2) Only valid with pre-applied Vincotech thermal interface material.

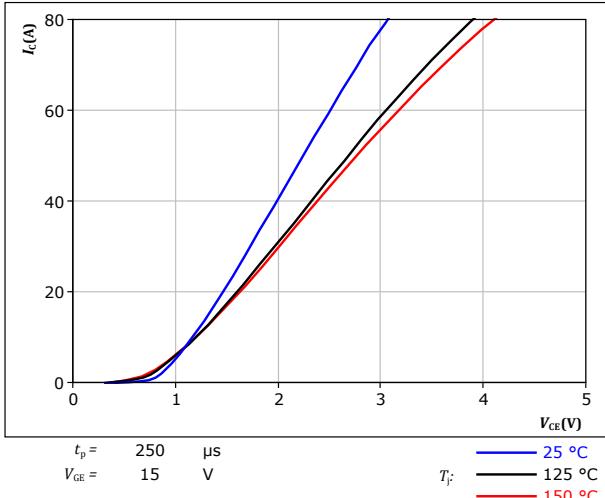


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## Inverter Switch Characteristics

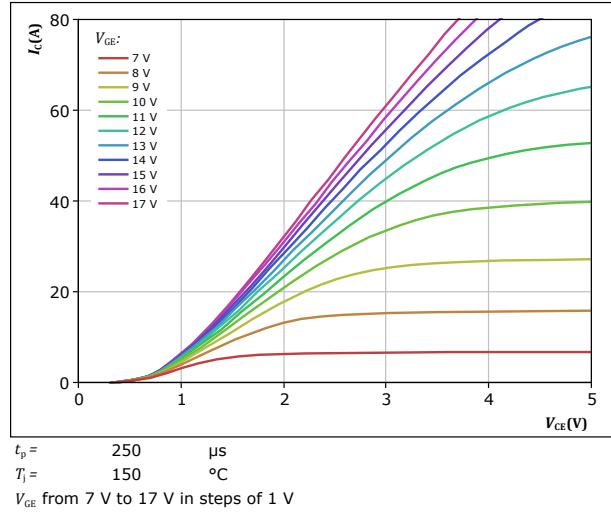
**figure 1.** IGBT

Typical output characteristics  
 $I_C = f(V_{CE})$



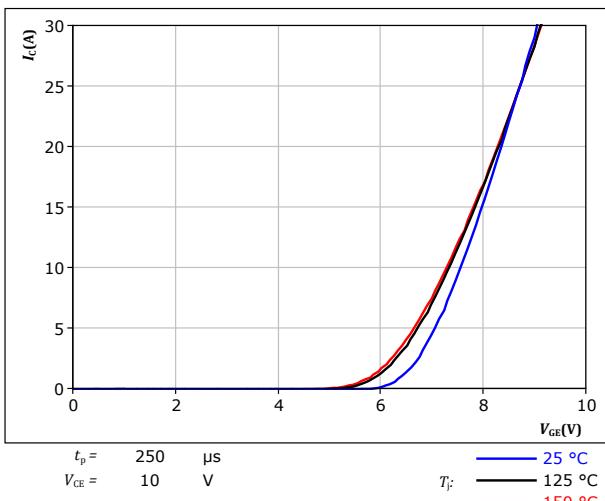
**figure 2.** IGBT

Typical output characteristics  
 $I_C = f(V_{CE})$



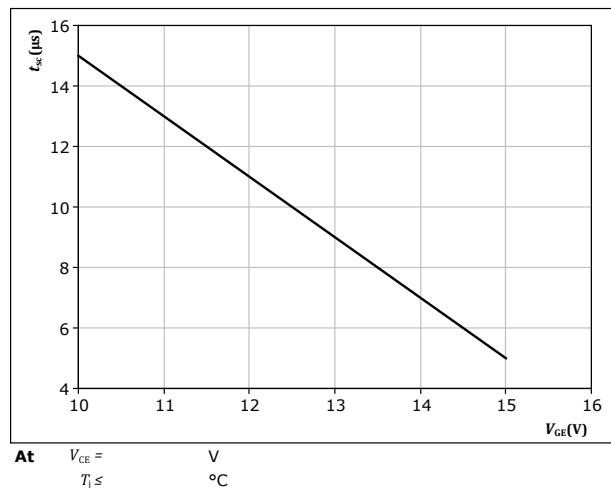
**figure 3.** IGBT

Typical transfer characteristics  
 $I_C = f(V_{GE})$



**figure 4.** IGBT

Short circuit withstand time as a function of  $V_{GE}$   
 $t_{sc} = f(V_{GE})$



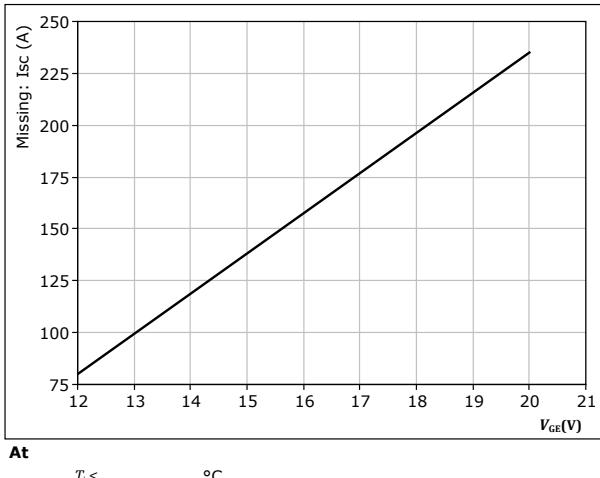


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## Inverter Switch Characteristics

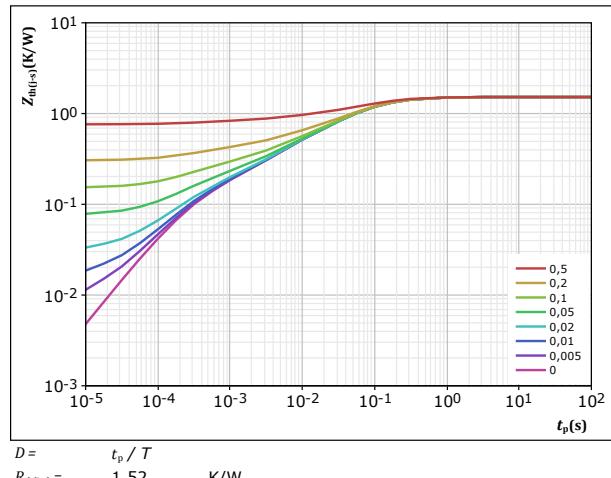
**figure 5.** IGBT

Typical short circuit current as a function of  $V_{GE}$   
Missing:  $ISC = f(V_{GE})$



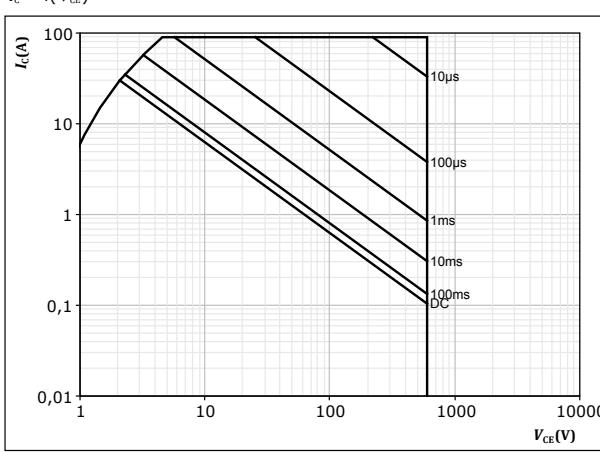
**figure 6.** IGBT

Transient thermal impedance as a function of pulse width  
 $Z_{th(j-s)} = f(t_p)$



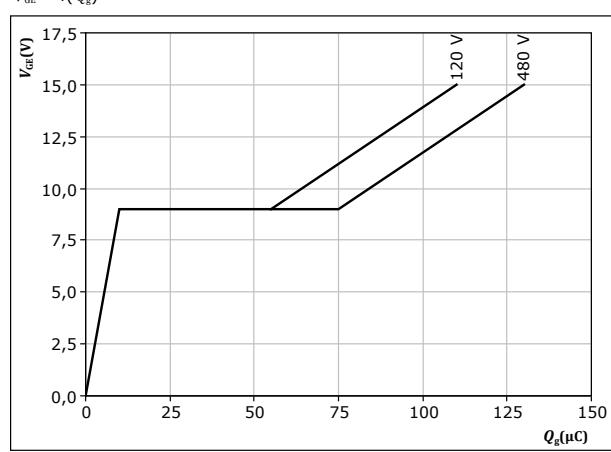
**figure 7.** IGBT

Safe operating area  
 $I_c = f(V_{CE})$



**figure 8.** IGBT

Gate voltage vs gate charge  
 $V_{GE} = f(Q_g)$





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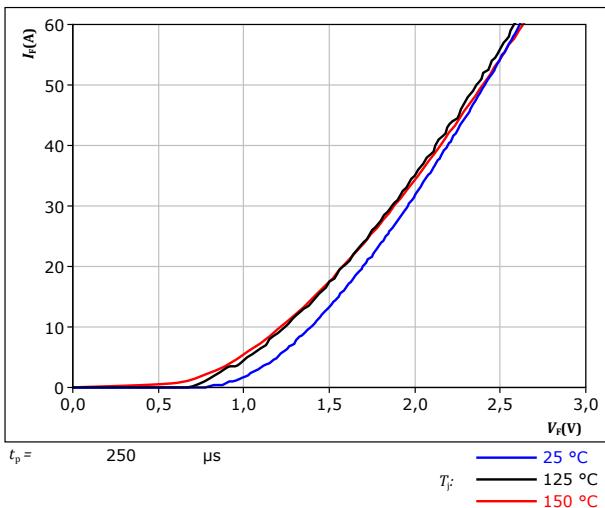
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## Inverter Diode Characteristics

figure 9.

Typical forward characteristics

$$I_F = f(V_F)$$

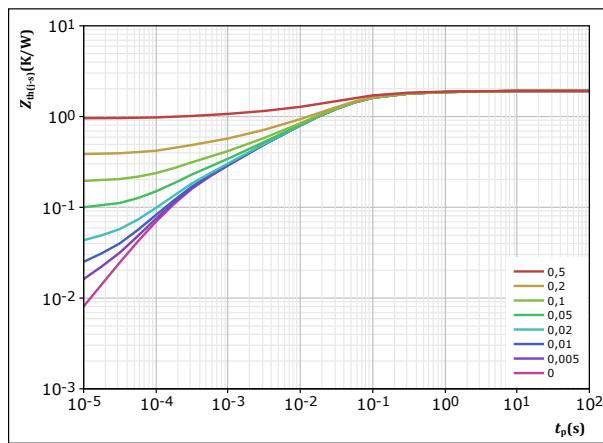


FWD

figure 10.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



FWD

$$D = \frac{t_p}{T} = 1,914 \text{ K/W}$$

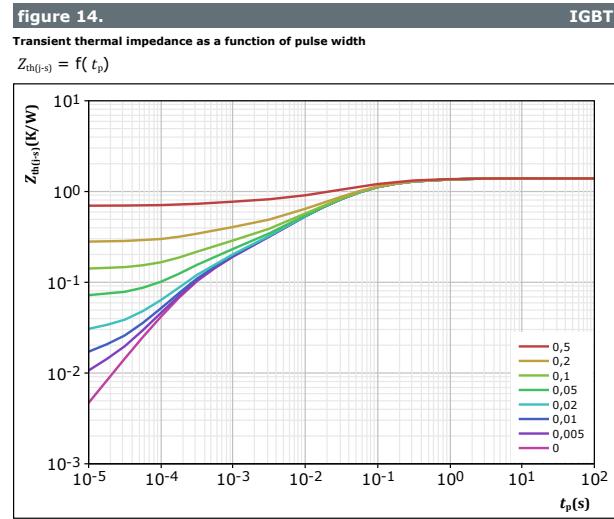
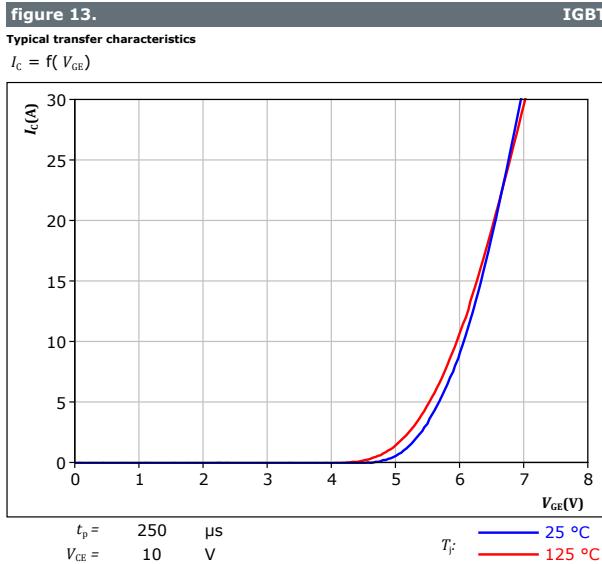
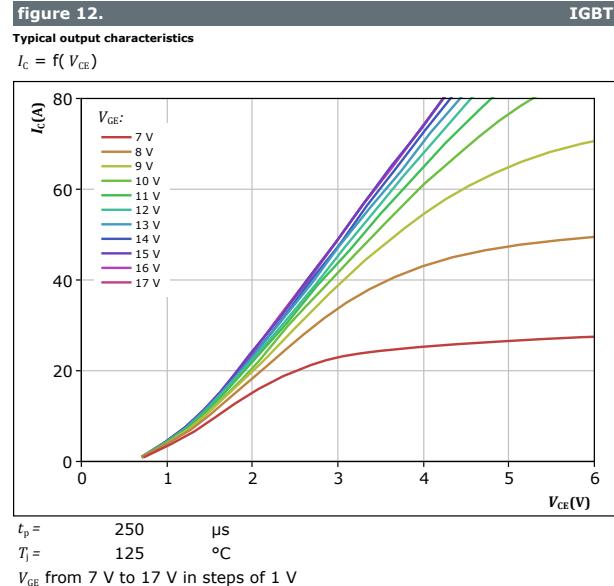
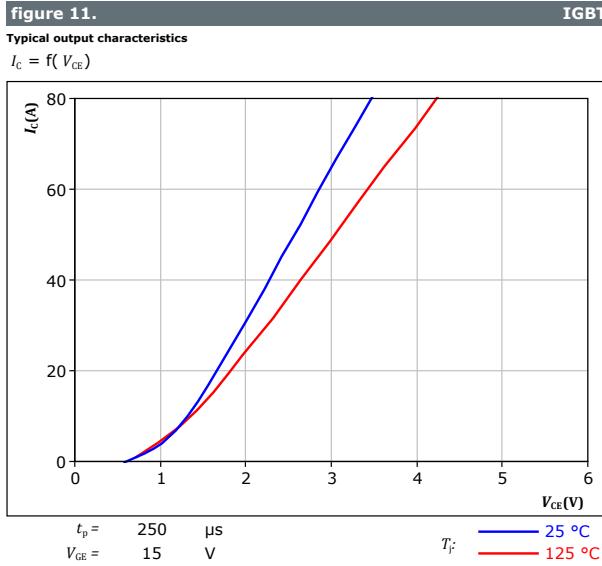
FWD thermal model values

$R$ (K/W)	$\tau$ (s)
8,07E-02	2,21E+00
2,18E-01	2,22E-01
8,50E-01	4,41E-02
4,32E-01	9,35E-03
2,00E-01	1,60E-03
1,34E-01	2,12E-04



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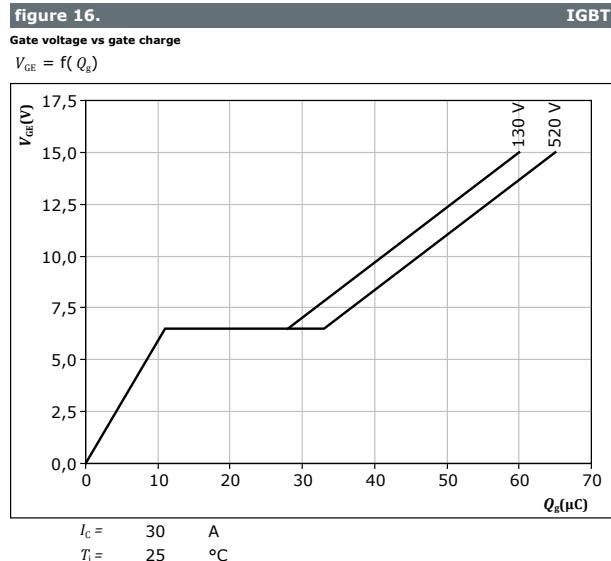
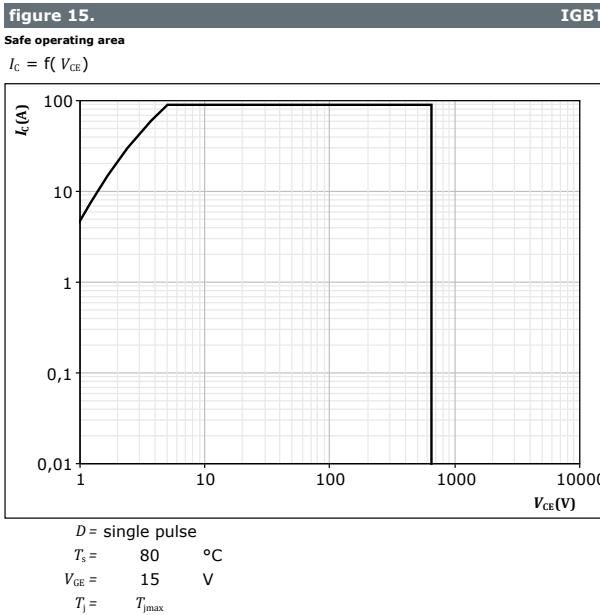
## PFC Switch Characteristics





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## PFC Switch Characteristics

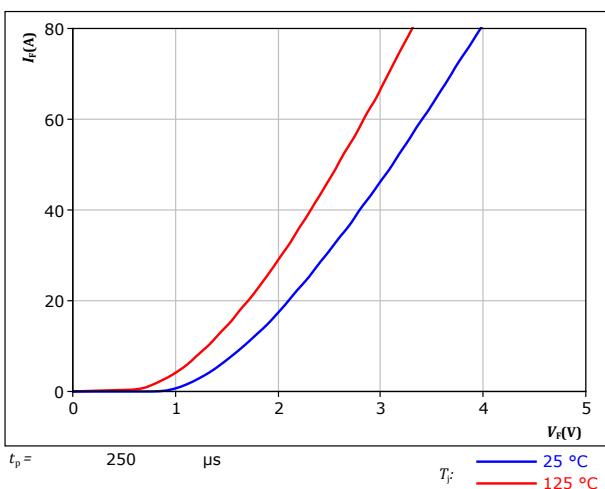




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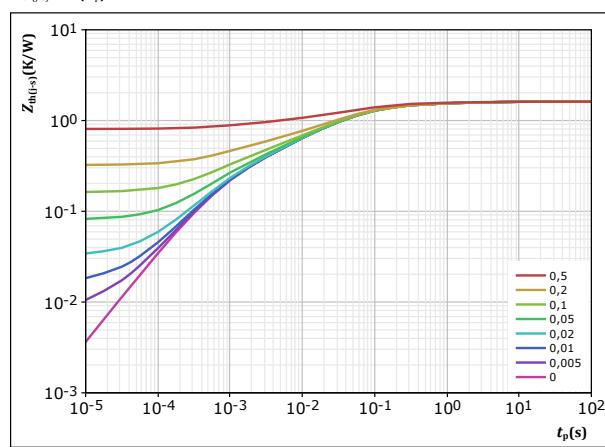
## PFC Diode Characteristics

**figure 17.**  
Typical forward characteristics  
 $I_F = f(V_F)$



FWD

**figure 18.**  
Transient thermal impedance as a function of pulse width  
 $Z_{th(j-s)} = f(t_p)$



FWD

$D = t_p / T$	$R_{th(j-s)} = 1,615 \text{ K/W}$
FWD thermal model values	
$R$ (K/W)	$\tau$ (s)
6,26E-02	3,75E+00
1,57E-01	4,48E-01
5,80E-01	7,07E-02
4,30E-01	1,76E-02
2,34E-01	3,12E-03
1,51E-01	5,87E-04



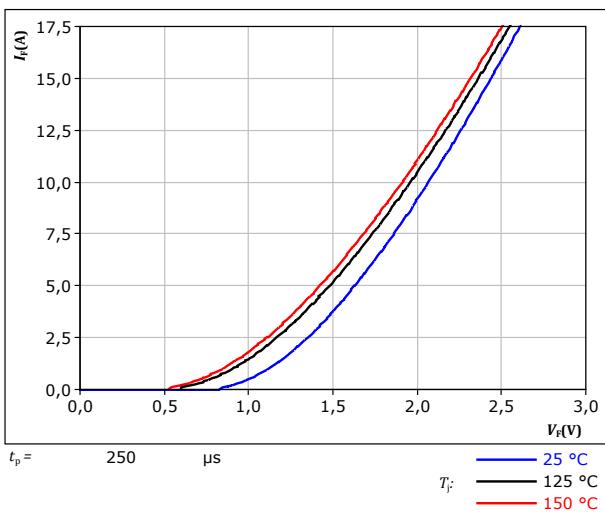
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## PFC Sw. Protection Diode Characteristics

figure 19.

Typical forward characteristics

$$I_F = f(V_F)$$

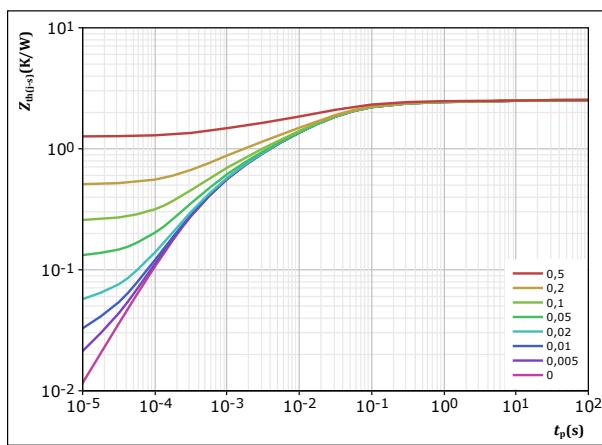


FWD

figure 20.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



FWD

$$D = \frac{t_p}{\tau} = \frac{t_p}{2,527} \quad K/W$$

FWD thermal model values

$R$ (K/W)	$\tau$ (s)
9,24E-02	9,29E+00
1,75E-01	3,21E-01
7,31E-01	4,97E-02
7,14E-01	1,16E-02
4,89E-01	2,11E-03
3,27E-01	3,78E-04

**10-FE06PPA030SJ07-LV82B03Z**

datasheet

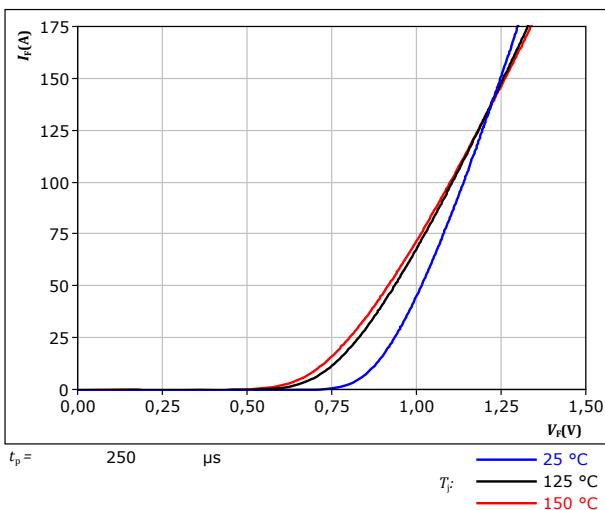
Vincotech

## Rectifier Diode Characteristics

**figure 21.**

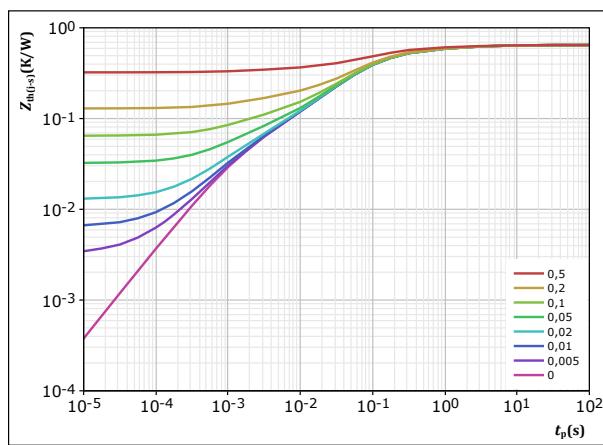
Typical forward characteristics

$$I_F = f(V_F)$$

**figure 22.**

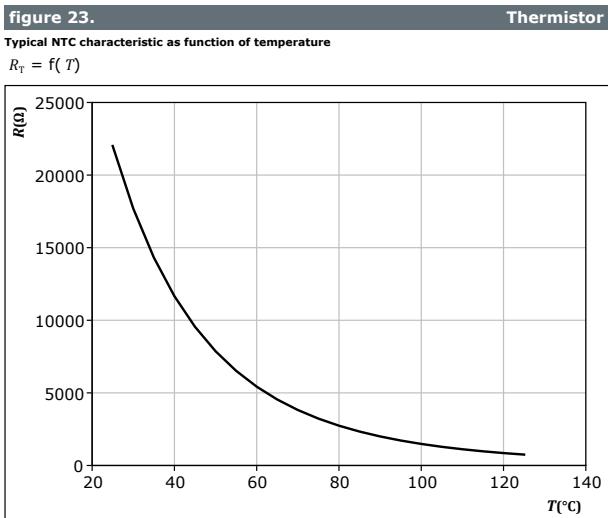
Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





## Thermistor Characteristics



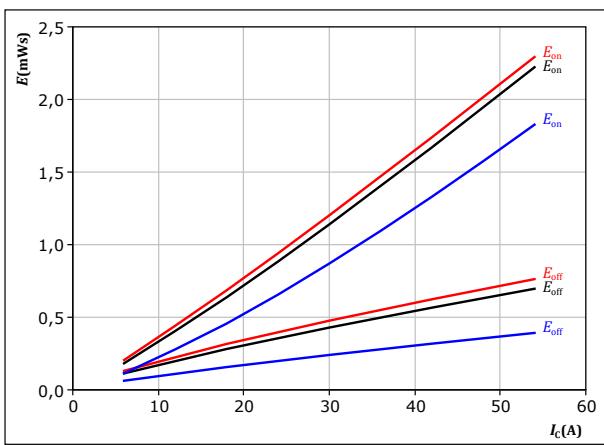


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## Inverter Switching Characteristics

figure 24.

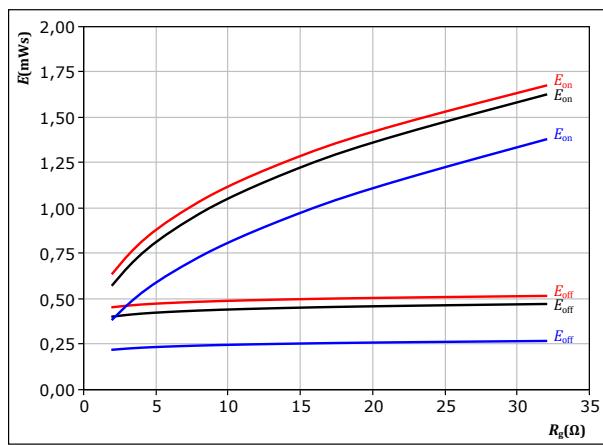
Typical switching energy losses as a function of collector current  
 $E = f(I_C)$



IGBT

figure 25.

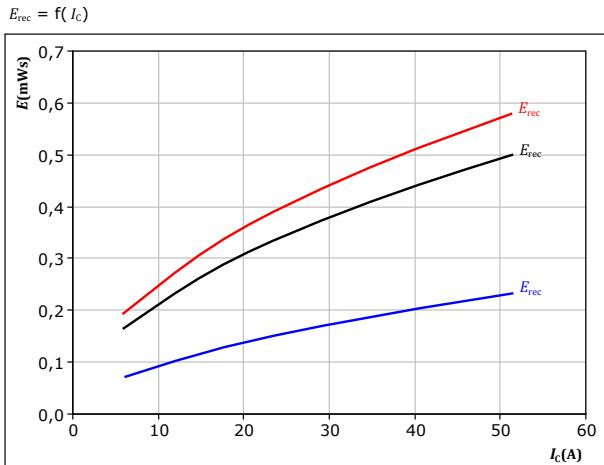
Typical switching energy losses as a function of gate resistor  
 $E = f(R_g)$



IGBT

figure 26.

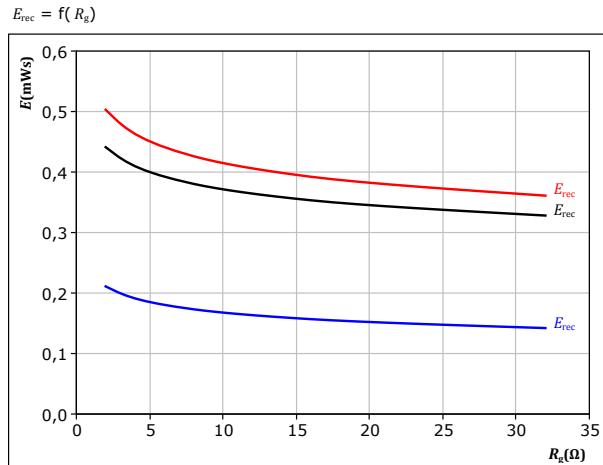
Typical reverse recovered energy loss as a function of collector current  
 $E_{rec} = f(I_C)$



FWD

figure 27.

Typical reverse recovered energy loss as a function of gate resistor  
 $E_{rec} = f(R_g)$



FWD

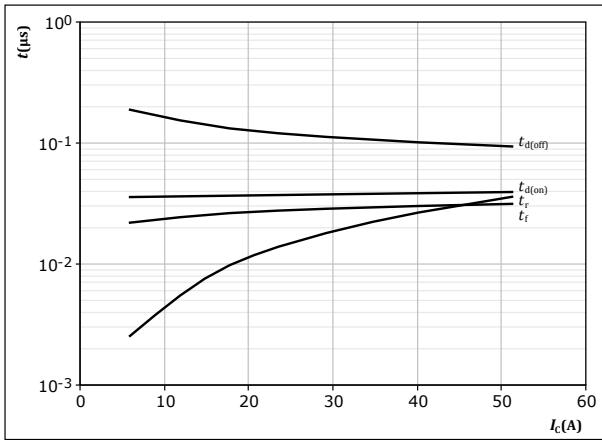


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## Inverter Switching Characteristics

**figure 28.**

Typical switching times as a function of collector current  
 $t = f(I_C)$



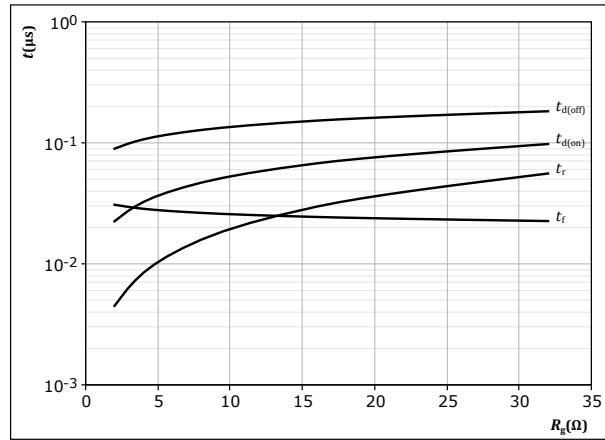
With an inductive load at

$T_j = 150^\circ\text{C}$   
 $V_{CE} = 350 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 8 \Omega$   
 $R_{goff} = 8 \Omega$

**IGBT**

**figure 29.**

Typical switching times as a function of gate resistor  
 $t = f(R_g)$



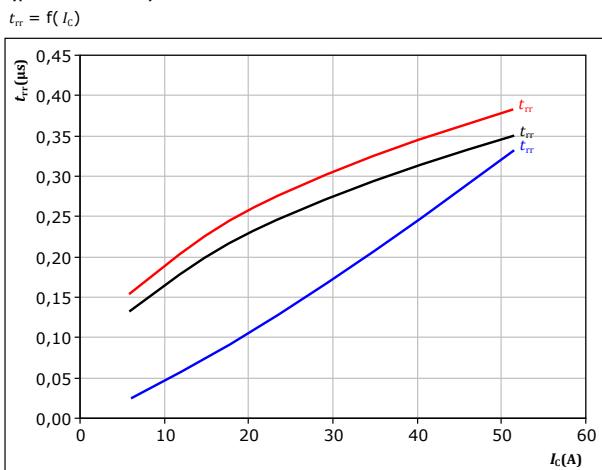
With an inductive load at

$T_j = 150^\circ\text{C}$   
 $V_{CE} = 350 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 30 \text{ A}$

**IGBT**

**figure 30.**

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_C)$



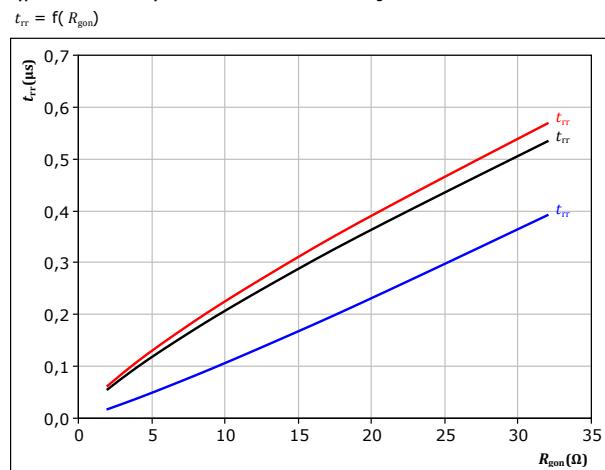
With an inductive load at

$V_{CE} = 350 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 8 \Omega$

**FWD**

**figure 31.**

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 350 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 30 \text{ A}$

**FWD**



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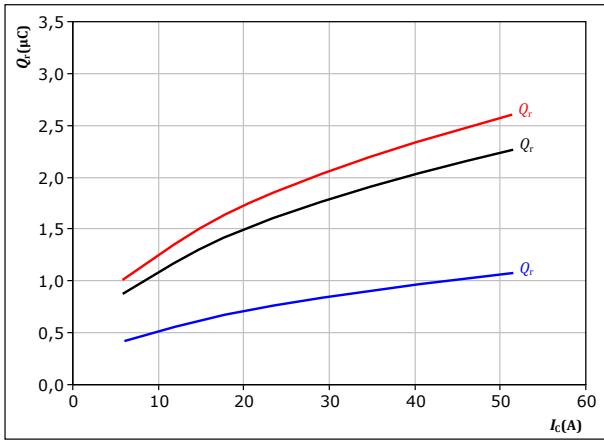
## Inverter Switching Characteristics

figure 32.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

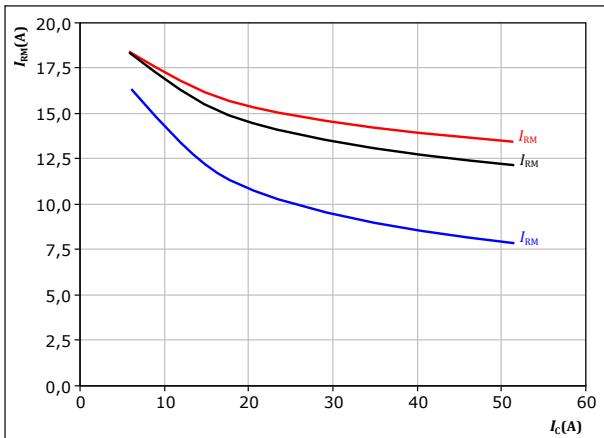
$V_{CE} = 350 \text{ V}$	$T_f: 25 \text{ }^{\circ}\text{C}$
$V_{GE} = \pm 15 \text{ V}$	$\text{---} 125 \text{ }^{\circ}\text{C}$
$R_{gon} = 8 \Omega$	$\text{---} 150 \text{ }^{\circ}\text{C}$

figure 34.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

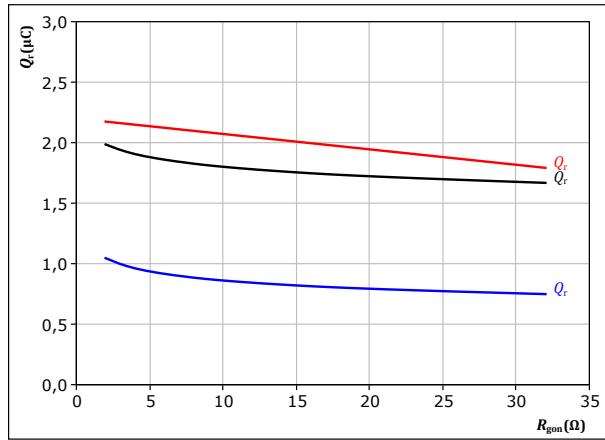
$V_{CE} = 350 \text{ V}$	$T_f: 25 \text{ }^{\circ}\text{C}$
$V_{GE} = \pm 15 \text{ V}$	$\text{---} 125 \text{ }^{\circ}\text{C}$
$R_{gon} = 8 \Omega$	$\text{---} 150 \text{ }^{\circ}\text{C}$

figure 33.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

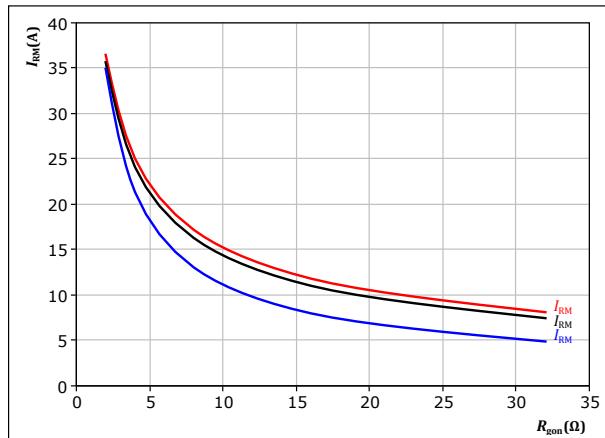
$V_{CE} = 350 \text{ V}$	$T_f: 25 \text{ }^{\circ}\text{C}$
$V_{GE} = \pm 15 \text{ V}$	$\text{---} 125 \text{ }^{\circ}\text{C}$
$I_c = 30 \text{ A}$	$\text{---} 150 \text{ }^{\circ}\text{C}$

figure 35.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 350 \text{ V}$	$T_f: 25 \text{ }^{\circ}\text{C}$
$V_{GE} = \pm 15 \text{ V}$	$\text{---} 125 \text{ }^{\circ}\text{C}$
$I_c = 30 \text{ A}$	$\text{---} 150 \text{ }^{\circ}\text{C}$

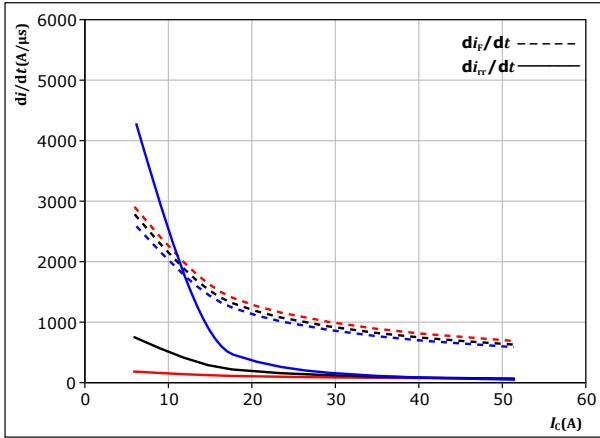


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## Inverter Switching Characteristics

figure 36. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_{rr}/dt = f(I_c)$

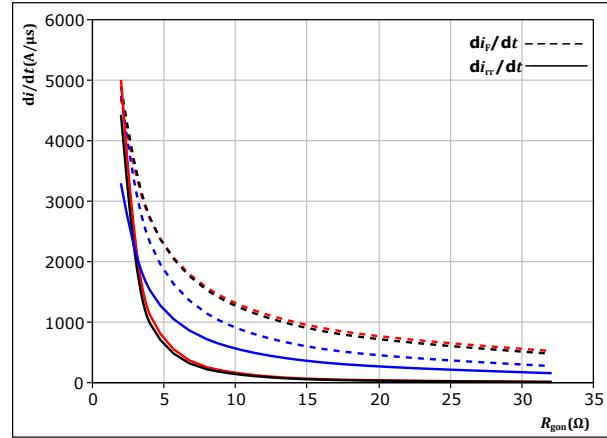


With an inductive load at

$V_{CE} = 350 \text{ V}$        $T_j = 25^\circ\text{C}$   
 $V_{GE} = \pm 15 \text{ V}$        $T_j = 125^\circ\text{C}$   
 $R_{gon} = 8 \Omega$        $T_j = 150^\circ\text{C}$

figure 37. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



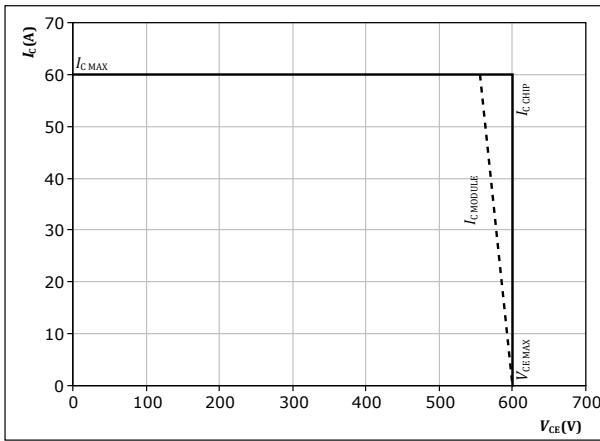
With an inductive load at

$V_{CE} = 350 \text{ V}$        $T_j = 25^\circ\text{C}$   
 $V_{GE} = \pm 15 \text{ V}$        $T_j = 125^\circ\text{C}$   
 $I_c = 30 \text{ A}$        $T_j = 150^\circ\text{C}$

figure 38. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At  $T_j = 150^\circ\text{C}$

$R_{gon} = 8 \Omega$   
 $R_{goff} = 8 \Omega$

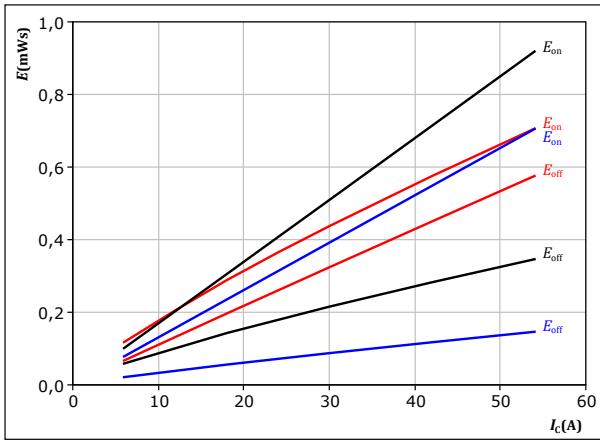


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## PFC Switching Characteristics

**figure 39.** IGBT

Typical switching energy losses as a function of collector current  
 $E = f(I_c)$

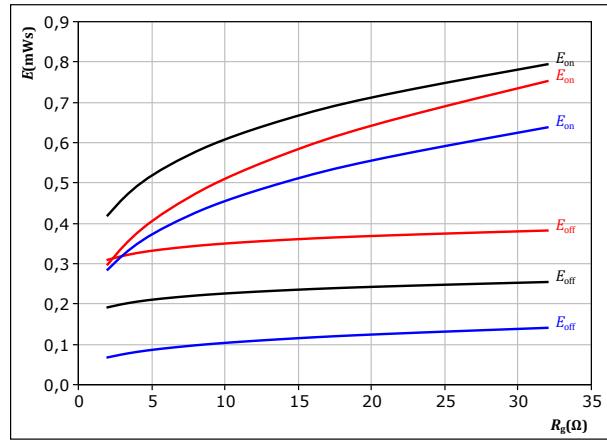


With an inductive load at

$V_{CE} = 400$  V       $T_f = 125$  °C  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 8 \Omega$   
 $R_{goff} = 8 \Omega$

**figure 40.** IGBT

Typical switching energy losses as a function of gate resistor  
 $E = f(R_g)$

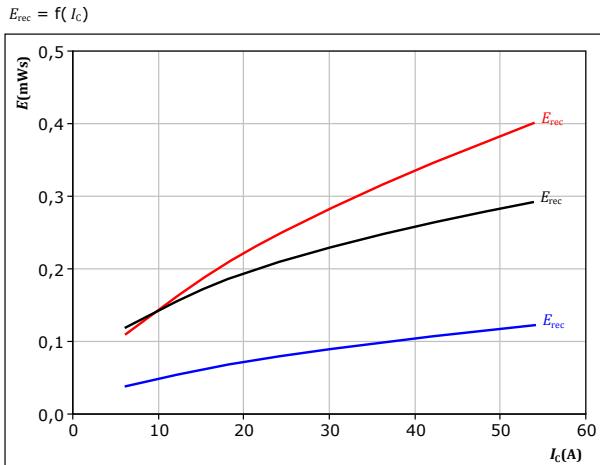


With an inductive load at

$V_{CE} = 400$  V       $T_f = 125$  °C  
 $V_{GE} = 0/15$  V  
 $I_c = 30$  A  
 $25$  °C      125 °C      150 °C

**figure 41.** FWD

Typical reverse recovered energy loss as a function of collector current  
 $E_{rec} = f(I_c)$

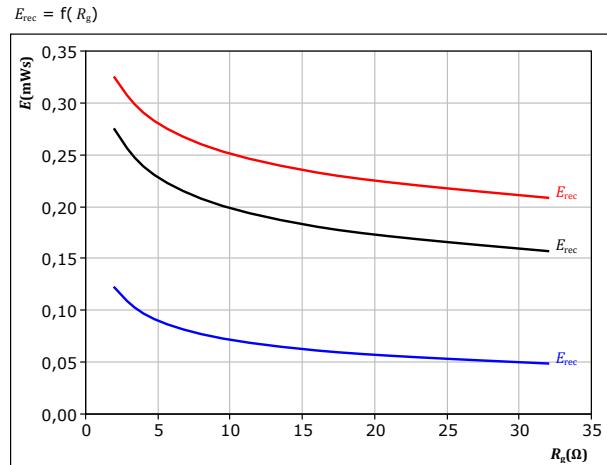


With an inductive load at

$V_{CE} = 400$  V       $T_f = 125$  °C  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 8 \Omega$

**figure 42.** FWD

Typical reverse recovered energy loss as a function of gate resistor  
 $E_{rec} = f(R_g)$



With an inductive load at

$V_{CE} = 400$  V       $T_f = 125$  °C  
 $V_{GE} = 0/15$  V  
 $I_c = 30$  A  
 $25$  °C      125 °C      150 °C

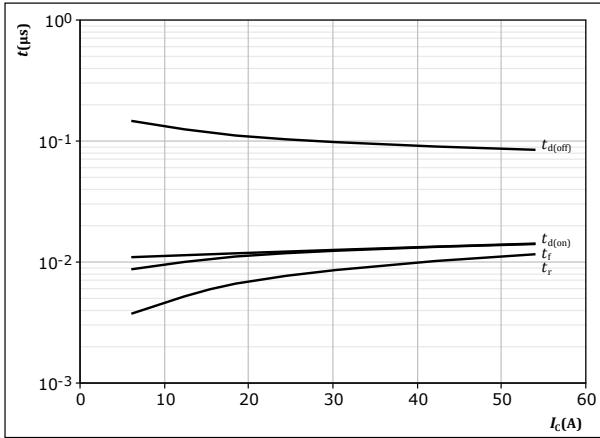


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## PFC Switching Characteristics

figure 43. IGBT

Typical switching times as a function of collector current  
 $t = f(I_C)$

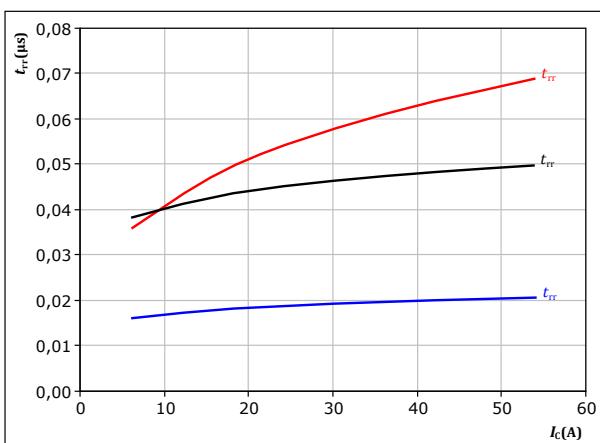


With an inductive load at

T<sub>j</sub> = 150 °C  
V<sub>CE</sub> = 400 V  
V<sub>GE</sub> = 0/15 V  
R<sub>gon</sub> = 8 Ω  
R<sub>gorf</sub> = 8 Ω

figure 45. FWD

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_C)$

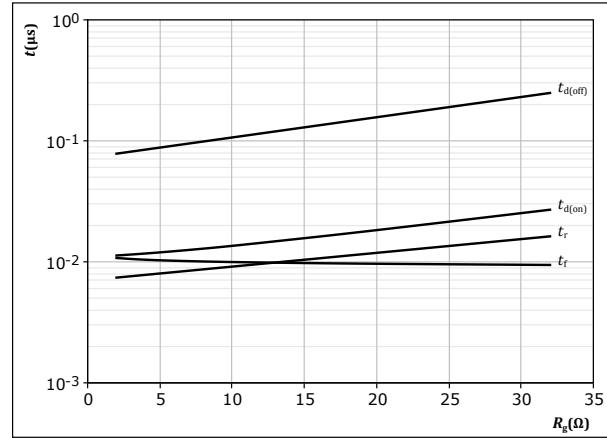


With an inductive load at

V<sub>CE</sub> = 400 V  
V<sub>GE</sub> = 0/15 V  
R<sub>gon</sub> = 8 Ω

figure 44. IGBT

Typical switching times as a function of gate resistor  
 $t = f(R_g)$

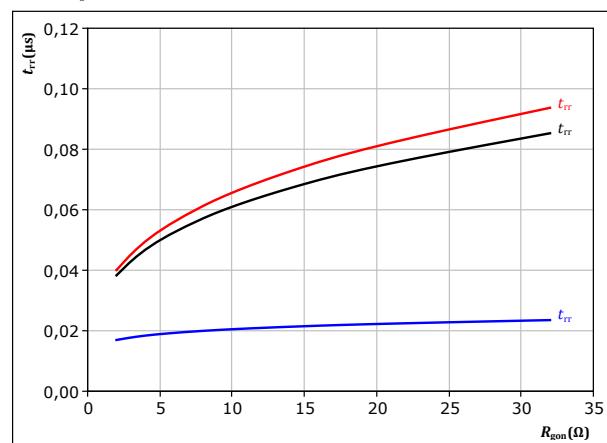


With an inductive load at

T<sub>j</sub> = 150 °C  
V<sub>CE</sub> = 400 V  
V<sub>GE</sub> = 0/15 V  
I<sub>C</sub> = 30 A

figure 46. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

V<sub>CE</sub> = 400 V  
V<sub>GE</sub> = 0/15 V  
I<sub>C</sub> = 30 A



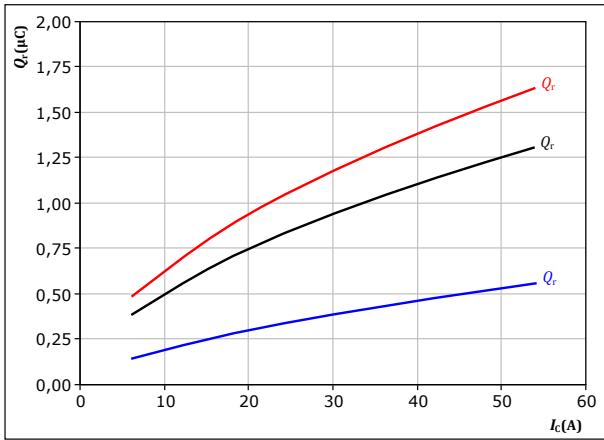
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## PFC Switching Characteristics

figure 47.

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

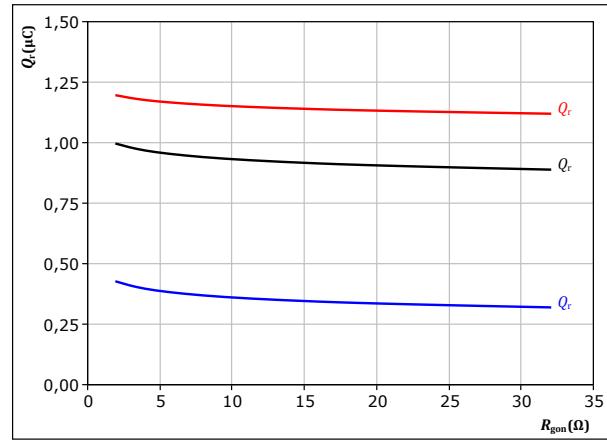
$$\begin{aligned} V_{CE} &= 400 \text{ V} & T_f &= 25 \text{ °C} \\ V_{GE} &= 0/15 \text{ V} & & \\ R_{gon} &= 8 \Omega & I_c &= 30 \text{ A} \end{aligned}$$

FWD

figure 48.

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

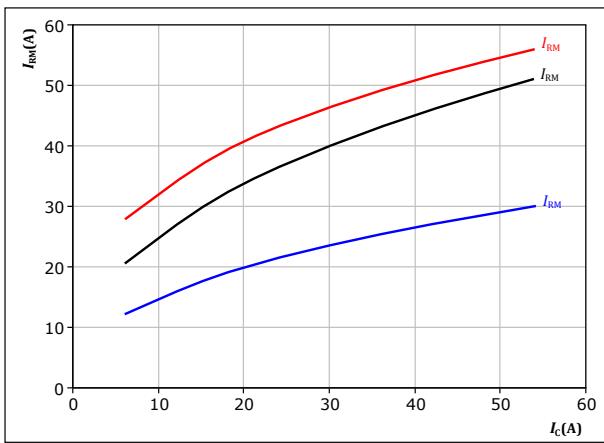
$$\begin{aligned} V_{CE} &= 400 \text{ V} & T_f &= 25 \text{ °C} \\ V_{GE} &= 0/15 \text{ V} & & \\ I_c &= 30 \text{ A} & R_{gon} &= 8 \Omega \end{aligned}$$

FWD

figure 49.

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

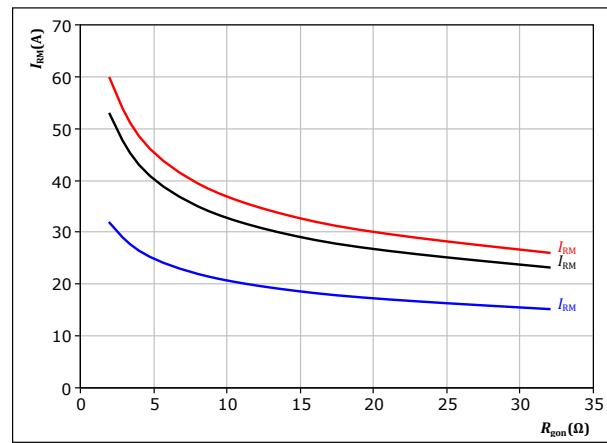
$$\begin{aligned} V_{CE} &= 400 \text{ V} & T_f &= 25 \text{ °C} \\ V_{GE} &= 0/15 \text{ V} & & \\ R_{gon} &= 8 \Omega & I_c &= 30 \text{ A} \end{aligned}$$

FWD

figure 50.

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \text{ V} & T_f &= 25 \text{ °C} \\ V_{GE} &= 0/15 \text{ V} & & \\ I_c &= 30 \text{ A} & R_{gon} &= 8 \Omega \end{aligned}$$

FWD



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## PFC Switching Characteristics

figure 51. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_f/dt, di_{rr}/dt = f(I_c)$

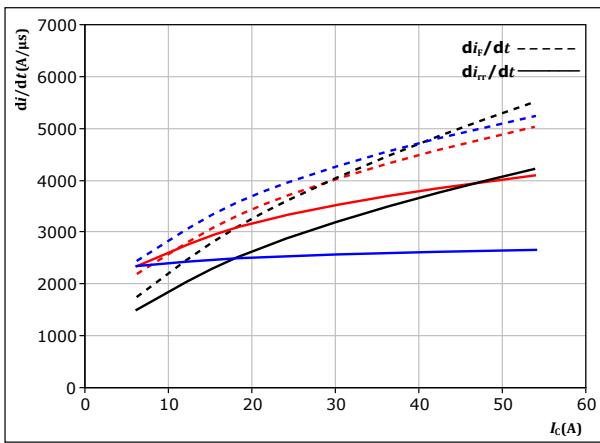


figure 52. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor

$di_f/dt, di_{rr}/dt = f(R_{gon})$

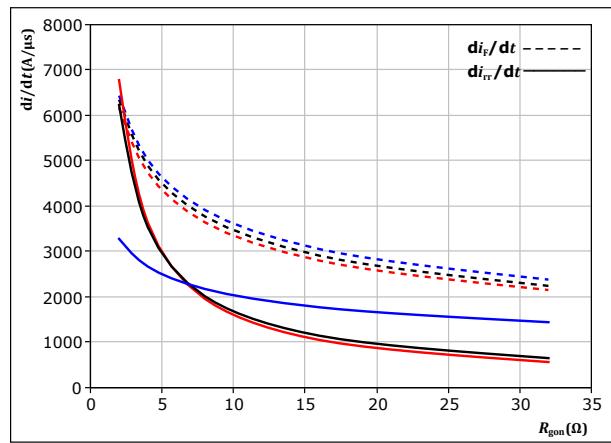
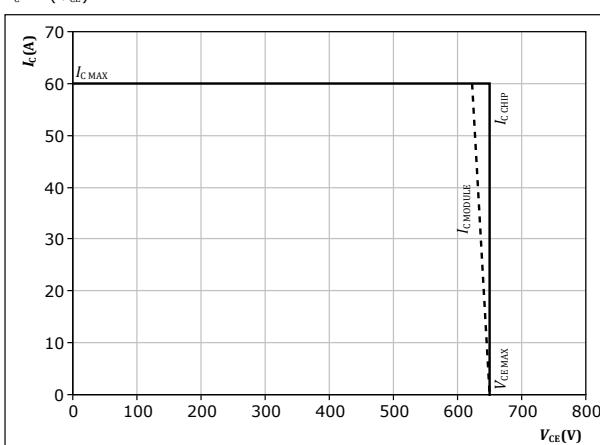


figure 53. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



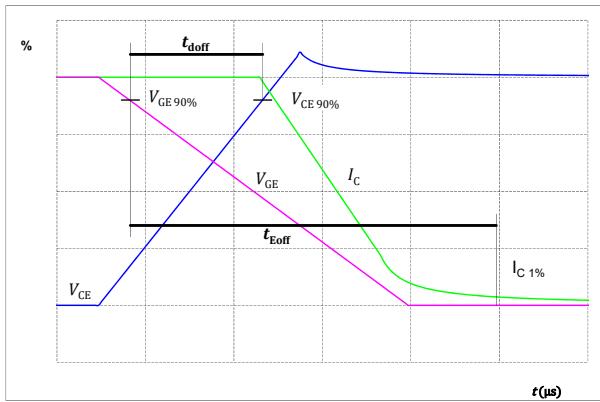


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## Switching Definitions

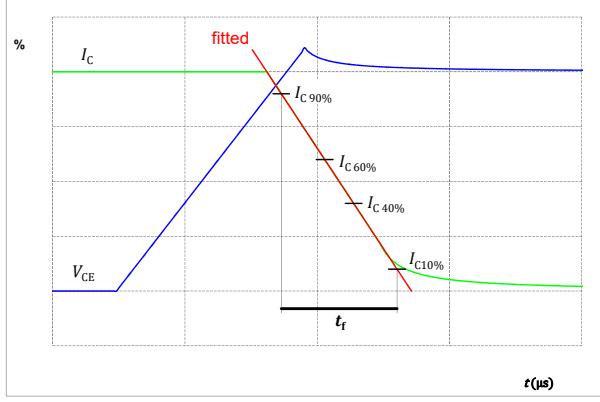
**figure 54.** IGBT

Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



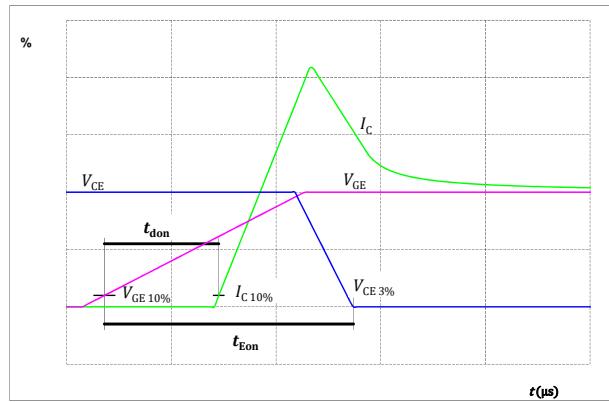
**figure 56.** IGBT

Turn-off Switching Waveforms & definition of  $t_f$



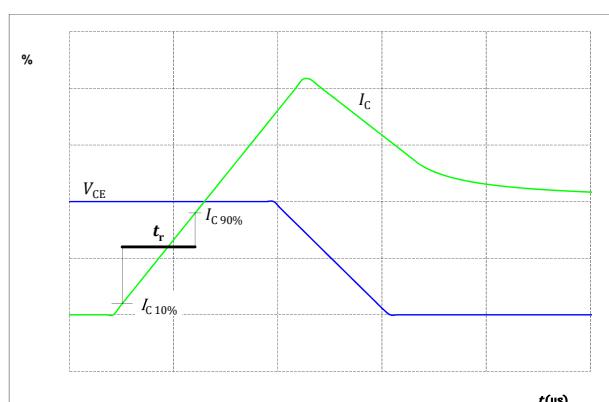
**figure 55.** IGBT

Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



**figure 57.** IGBT

Turn-on Switching Waveforms & definition of  $t_r$





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## Switching Definitions

figure 58.

Turn-off Switching Waveforms & definition of  $t_{tr}$

FWD

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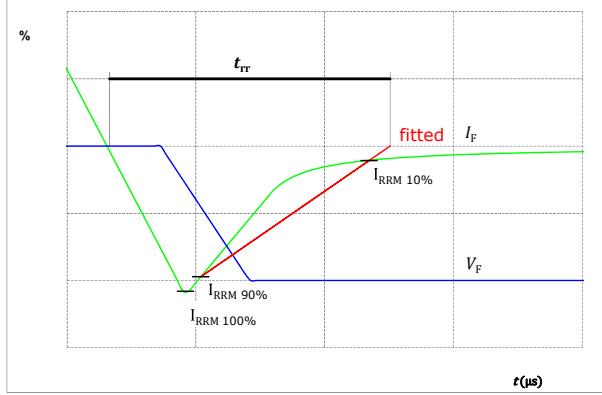
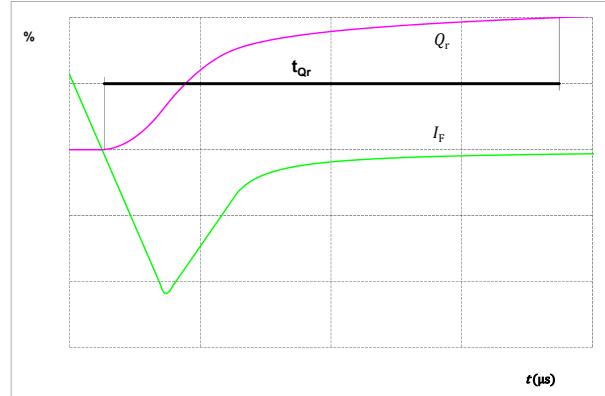


figure 59.

Turn-on Switching Waveforms & definition of  $t_{qr}$  ( $t_{qr}$  = integrating time for  $Q_r$ )

FWD

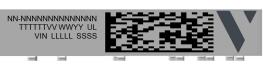
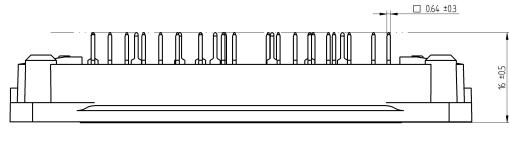
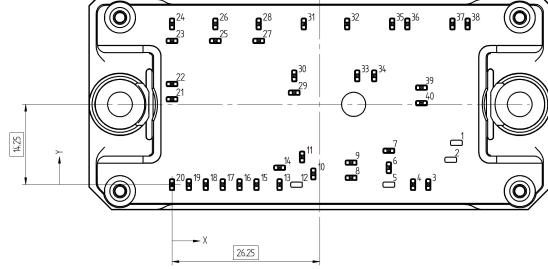
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**10-FE06PPA030SJ07-LV82B03Z**

datasheet

**Vincotech**

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<b>Pin table [mm]</b> <table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td></td><td></td><td>not assembled</td></tr><tr><td>2</td><td></td><td></td><td>not assembled</td></tr><tr><td>3</td><td>45,5</td><td>0</td><td>DC-Rect</td></tr><tr><td>4</td><td>42,8</td><td>0</td><td>DC-Rect</td></tr><tr><td>5</td><td></td><td></td><td>not assembled</td></tr><tr><td>6</td><td>38,5</td><td>3</td><td>PFC-1</td></tr><tr><td>7</td><td>38,5</td><td>6</td><td>PFC-1</td></tr><tr><td>8</td><td>31,8</td><td>1,2</td><td>PFC+</td></tr><tr><td>9</td><td>31,8</td><td>3,9</td><td>PFC+</td></tr><tr><td>10</td><td>25,1</td><td>1,9</td><td>PFC-2</td></tr><tr><td>11</td><td>23,1</td><td>4,9</td><td>PFC-2</td></tr><tr><td>12</td><td></td><td></td><td>not assembled</td></tr><tr><td>13</td><td>19,1</td><td>0</td><td>Therm1</td></tr><tr><td>14</td><td>19,1</td><td>3</td><td>Therm2</td></tr><tr><td>15</td><td>15</td><td>0</td><td>G11</td></tr><tr><td>16</td><td>12</td><td>0</td><td>DC-1</td></tr><tr><td>17</td><td>9</td><td>0</td><td>G13</td></tr><tr><td>18</td><td>6</td><td>0</td><td>DC-2</td></tr><tr><td>19</td><td>3</td><td>0</td><td>G15</td></tr><tr><td>20</td><td>0</td><td>0</td><td>DC-3</td></tr><tr><td>21</td><td>0</td><td>15,15</td><td>DC+Inv</td></tr><tr><td>22</td><td>0</td><td>17,85</td><td>DC+Inv</td></tr><tr><td>23</td><td>0</td><td>25,5</td><td>G16</td></tr><tr><td>24</td><td>0</td><td>28,5</td><td>Ph3</td></tr><tr><td>25</td><td>7,7</td><td>25,5</td><td>G14</td></tr><tr><td>26</td><td>7,7</td><td>28,5</td><td>Ph2</td></tr><tr><td>27</td><td>15,4</td><td>25,5</td><td>G12</td></tr><tr><td>28</td><td>15,4</td><td>28,5</td><td>Ph1</td></tr><tr><td>29</td><td>21,7</td><td>16,3</td><td>G27</td></tr><tr><td>30</td><td>21,7</td><td>19,3</td><td>S27</td></tr><tr><td>31</td><td>23,4</td><td>28,5</td><td>PFC2</td></tr><tr><td>32</td><td>31,1</td><td>28,5</td><td>PFC1</td></tr><tr><td>33</td><td>32,9</td><td>19,3</td><td>G25</td></tr><tr><td>34</td><td>35,9</td><td>19,3</td><td>S25</td></tr><tr><td>35</td><td>39,1</td><td>28,5</td><td>DC+Rect</td></tr><tr><td>36</td><td>41,8</td><td>28,5</td><td>DC+Rect</td></tr><tr><td>37</td><td>49,8</td><td>28,5</td><td>ACIn1</td></tr><tr><td>38</td><td>52,5</td><td>28,5</td><td>ACIn1</td></tr><tr><td>39</td><td>44,3</td><td>17,2</td><td>ACIn2</td></tr><tr><td>40</td><td>44,3</td><td>14,45</td><td>ACIn2</td></tr></tbody></table>	Pin	X	Y	Function	1			not assembled	2			not assembled	3	45,5	0	DC-Rect	4	42,8	0	DC-Rect	5			not assembled	6	38,5	3	PFC-1	7	38,5	6	PFC-1	8	31,8	1,2	PFC+	9	31,8	3,9	PFC+	10	25,1	1,9	PFC-2	11	23,1	4,9	PFC-2	12			not assembled	13	19,1	0	Therm1	14	19,1	3	Therm2	15	15	0	G11	16	12	0	DC-1	17	9	0	G13	18	6	0	DC-2	19	3	0	G15	20	0	0	DC-3	21	0	15,15	DC+Inv	22	0	17,85	DC+Inv	23	0	25,5	G16	24	0	28,5	Ph3	25	7,7	25,5	G14	26	7,7	28,5	Ph2	27	15,4	25,5	G12	28	15,4	28,5	Ph1	29	21,7	16,3	G27	30	21,7	19,3	S27	31	23,4	28,5	PFC2	32	31,1	28,5	PFC1	33	32,9	19,3	G25	34	35,9	19,3	S25	35	39,1	28,5	DC+Rect	36	41,8	28,5	DC+Rect	37	49,8	28,5	ACIn1	38	52,5	28,5	ACIn1	39	44,3	17,2	ACIn2	40	44,3	14,45	ACIn2	 	Tolerance of pinpositions: ±0.4mm at the end of pins. Dimension of coordinate axis is only offset without tolerance.
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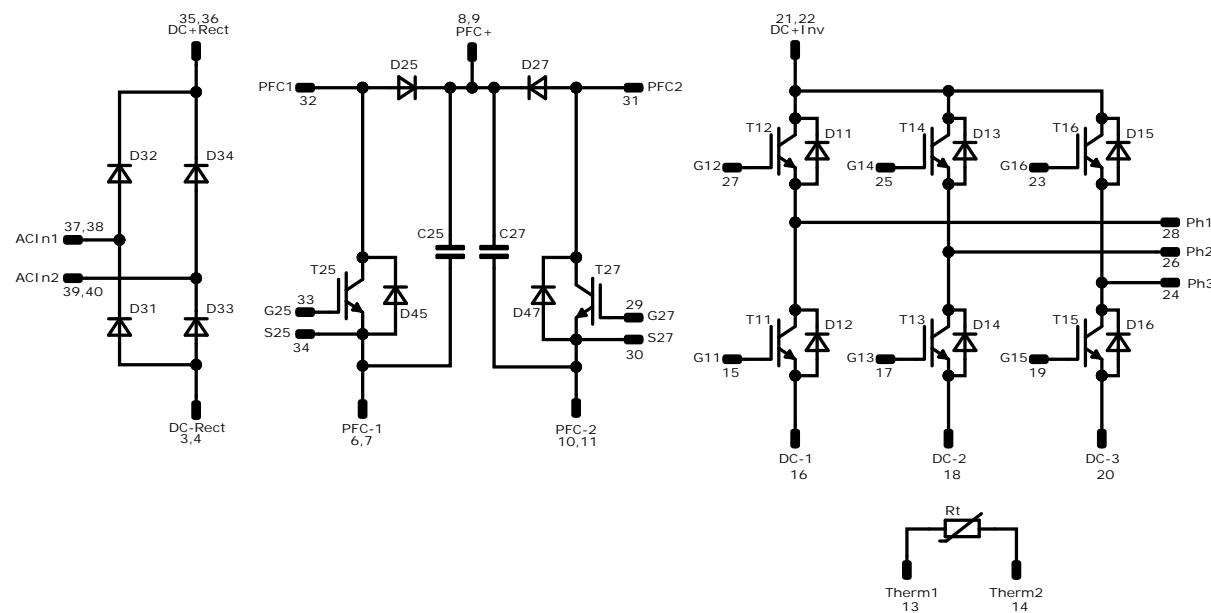


10-FE06PPA030SJ07-LV82B03Z

datasheet

Vincotech

## Pinout



## Identification

ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	600 V	30 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	600 V	20 A	Inverter Diode	
T25, T27	IGBT	650 V	30 A	PFC Switch	
D25, D27	FWD	650 V	30 A	PFC Diode	
D45, D47	FWD	650 V	6 A	PFC Sw. Protection Diode	
D31, D32, D33, D34	Rectifier	1600 V	60 A	Rectifier Diode	
C25, C27	Capacitor (PFC)	630 V		Capacitor (PFC)	
Rt	Thermistor			Thermistor	

**10-FE06PPA030SJ07-LV82B03Z**

datasheet

**Vincotech****Packaging instruction**

Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample
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**Handling instruction**

Handling instructions for flow 1 packages see vincotech.com website.

**Package data**

Package data for flow 1 packages see vincotech.com website.

**Vincotech thermistor reference**

See Vincotech thermistor reference table at vincotech.com website.

**UL recognition and file number**

This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-FE06PPA030SJ07-LV82B03Z-D1-14	8 Jan. 2021		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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